

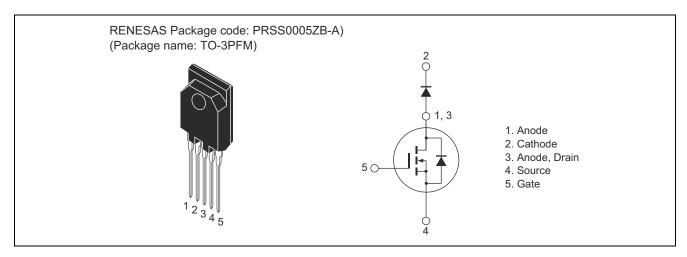
# RJQ6020DPM

600V - 20A - MOS FET High Speed Power Switching R07DS0649EJ0100 Rev.1.00 Jan 23, 2012

## **Features**

- High speed switching
- Low on-state voltage
- Built in fast recovery diode in one package

## **Outline**



# **Absolute Maximum Ratings**

MOS FET  $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	600	V
Gate to source voltage	$V_{GSS}$	+30, –20	V
Drain current	I <sub>D</sub> Note2	20	А
Drain peak current	I <sub>D(pulse)</sub> Note1	40	А
Body-drain diode reverse drain current	I <sub>DR</sub> Note2	20	А
Body-drain diode reverse drain peak current	I <sub>DR(pulse)</sub> Note1	40	А
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1.  $PW \le 10 \mu s$ , duty cycle  $\le 1\%$ 

2. Limited by maximum safe operating area.

Item	Symbol	Ratings	Unit
Maximum reverse voltage	$V_{RM}$	600	V
Continuous forward current	I <sub>F</sub>	10	A
Peak surge forward current	I <sub>FSM</sub>	20	A
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

RJQ6020DPM Preliminary

## **Electrical Characteristics**

 $MOS FET (Ta = 25 \degree C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	600	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	mA	$V_{DS} = 600 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = +30V, -20 V, V_{DS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	3	_	5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>	_	0.100	0.125	Ω	$I_D = 15 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note3, 4}}$
resistance						
Input capacitance	Ciss		2900		pF	V <sub>DS</sub> = 25 V
Output capacitance	Coss	_	3800	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	4	_	pF	f = 100 kHz
Body-drain diode forward voltage	$V_{DF}$	_	1.0	1.6	V	$I_F = 30 \text{ A}, V_{GS} = 0^{\text{Note3}}$

Notes: 3. Pulse test

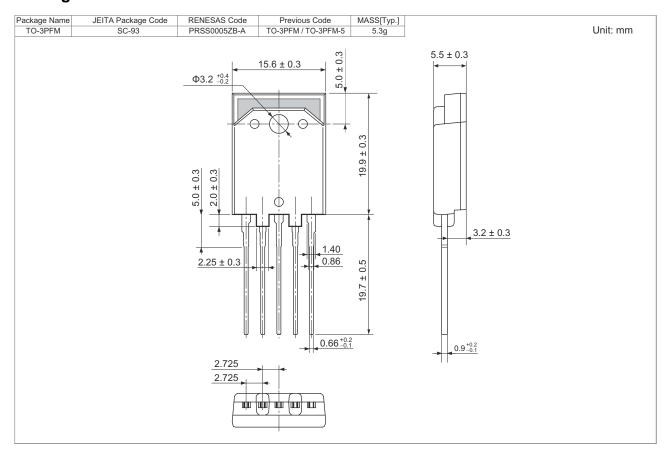
4. Value at pin 3 to pin 4.

 $\textbf{Diode} \hspace{1cm} (Tj = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Forward voltage	V <sub>F</sub>	_	1.5	2.0	V	I <sub>F</sub> = 10 A
Reverse current	$I_R$	_	_	10	μΑ	V <sub>R</sub> = 600 V
Reverse recovery time	t <sub>rr</sub>	_	15	_	ns	$I_F = 10 \text{ A}, \text{ di/dt} = -300 \text{A/}\mu\text{s}$

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# **Package Dimensions**



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